

# 1. Description

SS024N06TS, the N-channel Enhanced Power MOSFETs, is obtained by advanced double trench technology which reduce the conduction loss, improve switching performance and enhance the avalanche energy. This is suitable device for motor drivers and high speed switching applications.

## **KEY CHARACTERISTICS**

Parameter	Value	Unit
Vdss	60	V
lo	180	А
RDS(on).typ	2.1	mΩ

### FEATURES:

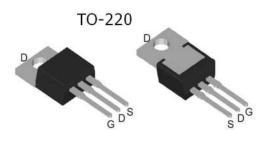
- Fast Switching
- Low On-Resistance (  $R_{DS(on)} \leq 2.4 m\Omega$  )
- Low Gate Charge
- Low Reverse transfer capacitances
- High avalanche ruggedness
- RoHS product

### **APPLICATIONS:**

- Switching applications
- Motor drivers
- BMS
- Synchronous rectification

### **ORDERING INFORMATION**

Ordering Codes	Package	Product Code	Packing
SS024N06TS	TO-220	SS024N06TS	Tube



Schematic Diagram

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